Con. 5205-09. S.E. (comp) Som III (R)

(REVISED COURSE)

Electronics Devices & Linear Circuits

N.B.: (1) Question No. 1 is compulsory.

- Attempt any four questions out of the remaining six questions. 2-30 P.M. Los (2)
- Assume suitable data if necessary.
- 1. (a) Explain the Purpose of a thin, Lightly doped base region of BJT Structure.
  - (b) Using practical OP-AMP realize following relation Vo=2V1+5V2+7V3-V4.
  - (c) Draw and explain the Block Diagram of Operational Amplifier.
  - (d) List Features of 555 Timer.
  - Justify how FET can be used as Variable resistor, constant current source and constant voltage source.
- 2. (a) Derive equations for Zi, Zo, Av for Common Source Configuration using voltage divider network (with Unbypassed Rs).
  - Determine  $V_C$  and  $V_B$  for the network shown (  $\beta = 120$ )

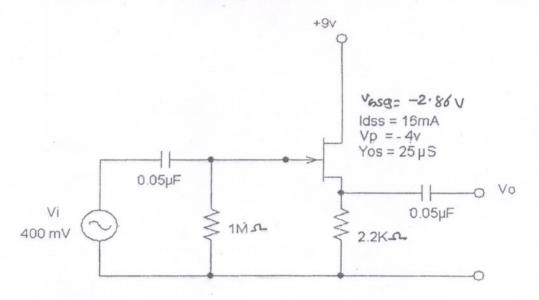
Vcc=+20v 2 8.7 K. 1 Rc ≥ 2.7 K.1 C1 10 µF Vi O-10 MF R2 \$ 2.2 K. Re \$ 1.8K. A

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(b) Calculate the voltage gain, input and output impedance for the circuit shown below. 10



Justify how FET can be used

- (a) PLL
  - (b) Inverting Schmitt Trigger
  - (c) Op-Amp as an Integrator.
  - (d) Features of Timer.